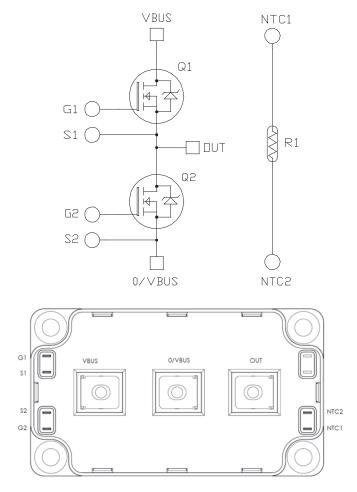
MSCSM70AM025T6AG

Phase Leg SiC MOSFET Power Module

Product Overview

The MSCSM70AM025T6AG device is a full bridge 700V, 689A phase leg silicon carbide (SiC) MOSFET power module.



Note: All ratings at $T_J = 25$ °C, unless otherwise specified.

⚠ CAUTION

These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are key features of the MSCSM70AM025T6AG device:

- SiC Power MOSFET
 - Low R_{DS(on)}
 - High temperature performance
- Kelvin source for easy drive
- Low stray inductance
- M5 power connectors
- Internal thermistor for temperature monitoring
- Aluminum Nitride (AIN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM70AM025T6AG device:

- · High efficiency converter
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Low profile
- RoHS compliant

Application

The MSCSM70AM025T6AG device is designed for the following applications:

- · Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

1. Electrical Specifications

This section provides the electrical specifications of the MSCSM70AM025T6AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings per SiC MOSFET of the MSCSM70AM025T6AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit
V _{DSS}	Drain-Source voltage		700	V
I _D			689 ¹	А
			548 ¹	
I _{DM}	Pulsed drain current		1380	
V _{GS}	Gate-Source voltage		-10/23	V
R _{DS(on)}	Drain-Source ON resistance		3.2	mΩ
P _D	Power dissipation	T _C = 25 °C	1882	W

Note:

 SiC MOSFET device specification, but the output current must be limited due to the size of the power connectors.

The following table lists the electrical characteristics per SiC MOSFET of the MSCSM70AM025T6AG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
I _{DSS}	Zero gate voltage drain current	V _{GS} = 0V V _{DS} = 700V		_	_	600	μΑ
R _{DS(on)}	Drain-Source on	V _{GS} = 20V	T _J = 25 °C	_	2.5	3.2	mΩ
	resistance I _D = 240A	T _J = 175 °C	_	3.2	_		
V _{GS(th)}	Gate threshold voltage	$V_{GS} = V_{DS}$ $I_D = 24 \text{ mA}$		1.9	2.4	_	V
I _{GSS}	Gate–Source leakage current	$V_{GS} = 20V$; $V_{DS} = 0V$		_	_	600	nA

The following table lists the dynamic characteristics per SiC MOSFET of the MSCSM70AM025T6AG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
C _{iss}	Input capacitance	V _{GS} = 0V		_	27	_	nF
C _{oss}	Output capacitance	V _{DS} = 700V	V _{DS} = 700V		3	_	
C _{rss}	Reverse transfer capacitance	f = 1 MHz		_	0.17	_	
Q_g	Total gate charge	V _{GS} = -5V/20V		_	1290	_	nC
Q _{gs}	Gate-Source charge	V _{Bus} = 470V I _D = 240A		_	348	_	
Q_{gd}	Gate-Drain charge			_	210	_	
T _{d(on)}	Turn-on delay time	V _{GS} = -5V/20V	T _J = 150°C	_	78	_	ns
T _r	Rise time	V _{Bus} = 400V		_	125	_	
T _{d(off)}	Turn-off delay time	I _D = 480A		_	214	_	
T _f	Fall time	$R_{G(on)} = 12\Omega$ $R_{G(off)} = 2.7\Omega$			92	_	
Eon	Turn-on energy	V _{GS} = -5V/20V	T _J = 150 °C	_	10	_	mJ
E _{off}	Turn-off energy	$V_{Bus} = 400V$ $I_{D} = 480A$ $R_{G(on)} = 12\Omega$ $R_{G(off)} = 2.7\Omega$	T _J = 150 °C	_	10.5	_	
R _{Gint}	Internal gate resistance			_	0.95	_	Ω
R _{thJC}	Junction-to-case thermal resistance			_	_	0.08	°C/W

The following table lists the body diode ratings and characteristics per SiC MOSFET of the MSCSM70AM025T6AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min.	Тур.	Max.	Unit
V _{SD}	Diode forward voltage	V _{GS} = 0V; I _{SD} = 240A	_	3.4	_	V
		$V_{GS} = -5V$; $I_{SD} = 240A$	_	3.8	_	
t _{rr}	Reverse recovery time	$I_{SD} = 240A; V_{GS} = -5V$	_	40	_	ns
Q _{rr}	Reverse recovery charge	$V_R = 400V$; $di_F/dt = 6000 A/\mu s$	_	1.9	_	μC
Irr	Reverse recovery current		_	89	_	Α

1.2 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM70AM025T6AG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristics	Characteristics			Max	Unit
V _{ISOL}	RMS isolation voltage, any terminal to	RMS isolation voltage, any terminal to case t =1 min, 50 Hz/60 Hz			_	V
T _J	Operating junction temperature range	Operating junction temperature range			175	°C
T _{JOP}	Recommended junction temperature ur	Recommended junction temperature under switching conditions				
T _{STG}	Storage temperature range	Storage temperature range			125	
T _C	Operating case temperature	Operating case temperature			125	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package weight	Package weight			300	g

The following table lists the temperature sensor NTC of the MSCSM70AM025T6AG device.

Table 1-6. Temperature Sensor NTC

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance at 25°C		_	50	_	kΩ
$\Delta R_{25}/R_{25}$	_	_	_	5	_	%
B _{25/85}	T ₂₅ = 298.15 K	_	_	3952	_	K
ΔΒ/Β	_	T _C = 100 °C	_	4	_	%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature} \quad R_T: \text{Thermistor value at T}$$

Note: See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

1.3 Typical SiC MOSFET Performance Curve

This section shows the typical SiC MOSFET performance curves of the MSCSM70AM025T6AG device.

Figure 1-1. Maximum Thermal Impedance

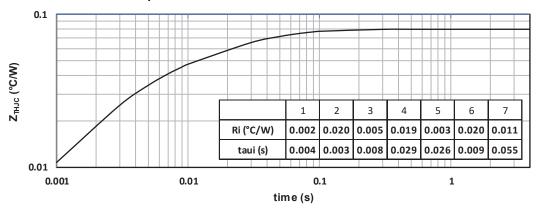


Figure 1-2. Output Characteristics, $T_J = 25$ °C

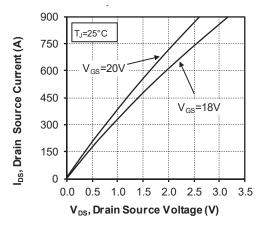


Figure 1-4. Normalized R_{DS(on)} vs. Temperature

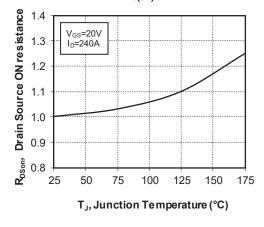


Figure 1-3. Output Characteristics, T_J = 175 °C

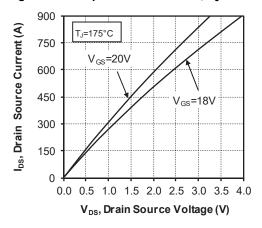


Figure 1-5. Transfer Characteristics

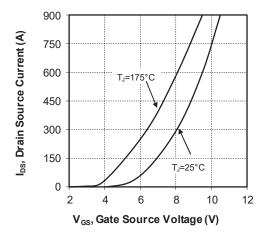


Figure 1-6. Switching Energy vs. Current

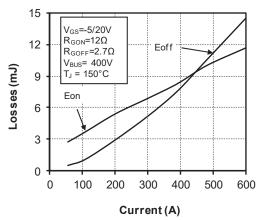


Figure 1-7. Turn On Energy vs. Rg

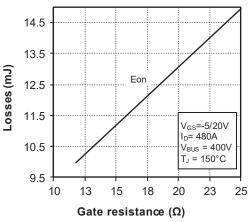


Figure 1-8. Capacitance vs. Drain Source Voltage

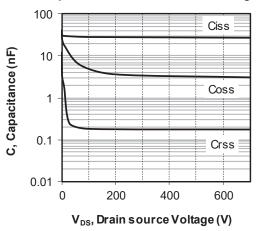


Figure 1-9. Gate Charge vs. Gate Source Voltage

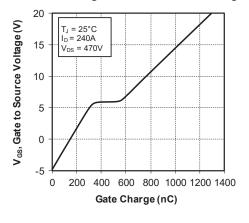


Figure 1-10. Body Diode Characteristics, T_J = 25 °C

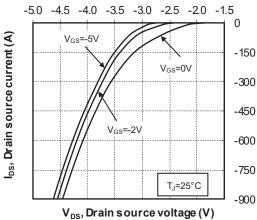


Figure 1-11. 3rd Quadrant Characteristics, T_J = 25 °C

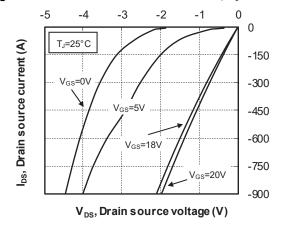
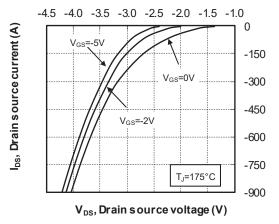


Figure 1-12. Body Diode Characteristics, T_J = 175 °C Figure 1-13. 3rd Quadrant Characteristics, T_J = 175 °C



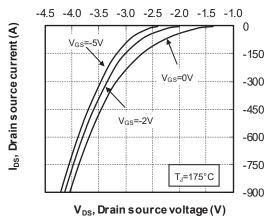


Figure 1-14. Operating Frequency vs Drain Current

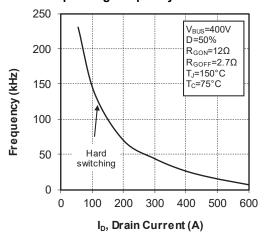
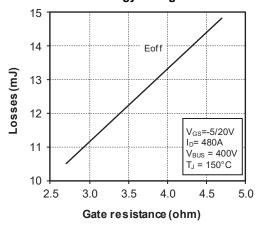


Figure 1-15. Turn Off Energy vs. Rg



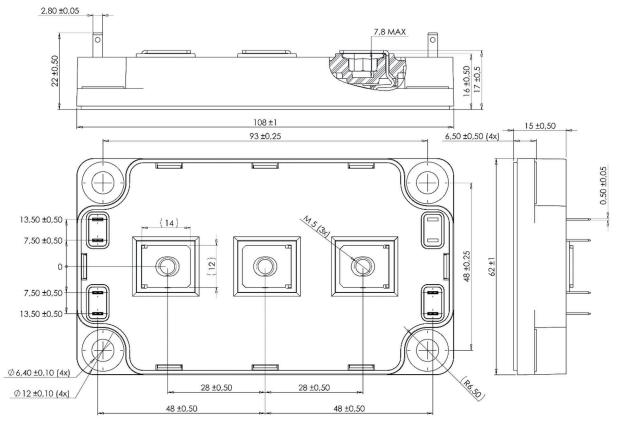
2. Package Specifications

The following section shows the package specification of the MSCSM70AM025T6AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM70AM025T6AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: See APT0601—Mounting Instructions for SP6 Power Modules for more information.

MSCSM70AM025T6AG

Revision History

3. Revision History

Revision	Date	Description
Α	06/2022	Initial Revision.

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